NSN 5961-00-951-8877



Transistor - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5961-00-951-8877 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 1.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: in the reverse direction with respect to the base **Current Rating Per Characteristic:**

6.0 emitter to base voltage, dc and 1.0 dc, open-circuit voltage, floating potential, between the collector and base, with the emitter biased

750.00 milliamperes source cutoff current blank

Power Rating Per Characteristic:

10.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius junction

Special Features:

Junction pattern arrangement: npn

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

3 uninsulated wire lead

Specification Data:

81349-mil-s-19500/263 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

NSN 5961-00-951-8877 Transistor - Page 2 of 2



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